

SPTECH Silicon PNP Power Transistor

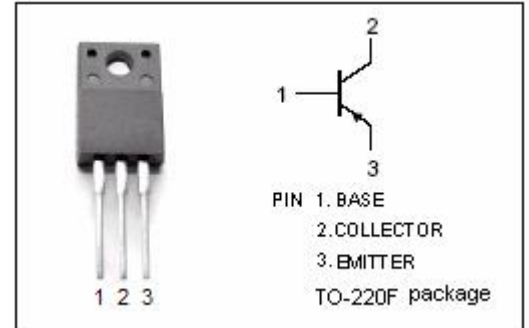
2SA1744

DESCRIPTION

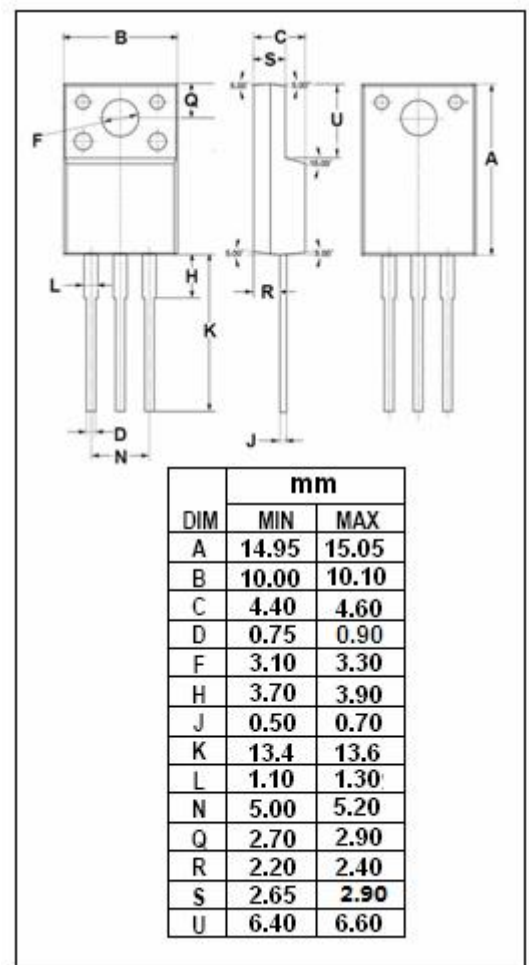
- With TO-220F package
- High h_{FE} and low $V_{CE(sat)}$

APPLICATIONS

- For high-speed switching
- For use in drivers such as DC-DC converters and actuators.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	-100	V
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-7.0	V
I_C	Collector Current-Continuous	-15	A
I_{CM}	Collector Current-Pulse	-30	A
I_B	Base Current-Continuous	-7.5	A
P_T	Total Power Dissipation @ $T_c=25^\circ\text{C}$	30	W
	Total Power Dissipation @ $T_a=25^\circ\text{C}$	2.0	
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$



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ELECTRICAL CHARACTERISTICS

T_j=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -8.0A ; I _B = -0.8A, L= 1mH	-60			V
V _{CES(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -8.0A ; I _{B1} =-I _{B2} = -0.8A, V _{BE(OFF)} =1.5V, L=180 μ H,clamped	-60			V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	I _C = -8A; I _B = -0.4A			-0.8	V
V _{BE(sat)-1}	Base-Emitter Saturation Voltage	I _C = -8A; I _B = -0.4A			-1.8	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -60V ; I _E =0			-10	μ A
I _{CER}	Collector Cutoff Current	V _{CE} = -60V ; R _{BE} = 50 Ω ,T _a =125°C			-1.0	mA
I _{CEX}	Collector Cutoff Current	V _{CE} = -60V; V _{BE(off)} = -1.5V V _{CE} = -60V; V _{BE(off)} = -1.5V,T _a =125°C			-10 -1.0	μ A mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C =0			-10	μ A
h _{FE-1}	DC Current Gain	I _C = -1.5A; V _{CE} = -2V	100			
h _{FE-2}	DC Current Gain	I _C = -3.0A; V _{CE} = -2V	100		400	
h _{FE-3}	DC Current Gain	I _C = -8.0A; V _{CE} = -2V	60			
C _{OB}	Output Capacitance	I _E =0; V _{CB} = -10V; f= 1.0MHz		300		pF
f _T	Current-Gain—Bandwidth Product	I _C = -1.5A; V _{CE} = -10V		80		MHz

Switching times

t _{on}	Turn-on Time	I _C = -8.0A, R _L = 6.3 Ω , I _{B1} = -I _{B2} = -0.4A, V _{CC} ≈ -50V			0.3	μ s
t _{stg}	Storage Time				1.5	μ s
t _f	Fall Time				0.3	μ s

◆ h_{FE-2} Classifications

M	L	K
100-200	150-300	200-400